

30V N-Channel PowerTrench[®] MOSFET

General Description

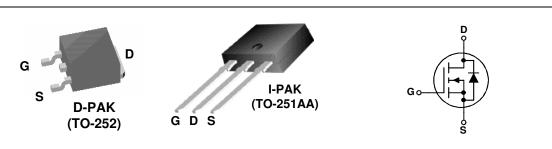
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

Applications

- DC/DC converter
- Motor Drives

Features

- 84 A, 30 V. $\begin{array}{l} R_{DS(ON)} = 5 \ m\Omega \ @ \ V_{GS} = 10 \ V \\ R_{DS(ON)} = 6 \ m\Omega \ @ \ V_{GS} = 4.5 \ V \end{array}$
- Low gate charge
- Fast switching
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$



Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbo I	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		30	V
V _{GSS}	Gate-Source Voltage		±20	
I _D	Drain Current – Continuous	(Note 3)	84	А
	– Pulsed	(Note 1a)	100	
PD	Power Dissipation for Single Operation	(Note 1)	83	W
		(Note 1a)	3.8	
		(Note 1b)	1.6	
T _J , T _{STG}	Operating and Storage Junction Temperat	ure Range	-55 to +175	°C

Thermal Characteristics

R _{eJC}	Thermal Resistance, Junction-to-Case	(Note 1)	1.8	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	40	
		(Note 1b)	96	

Package Marking and Ordering Information

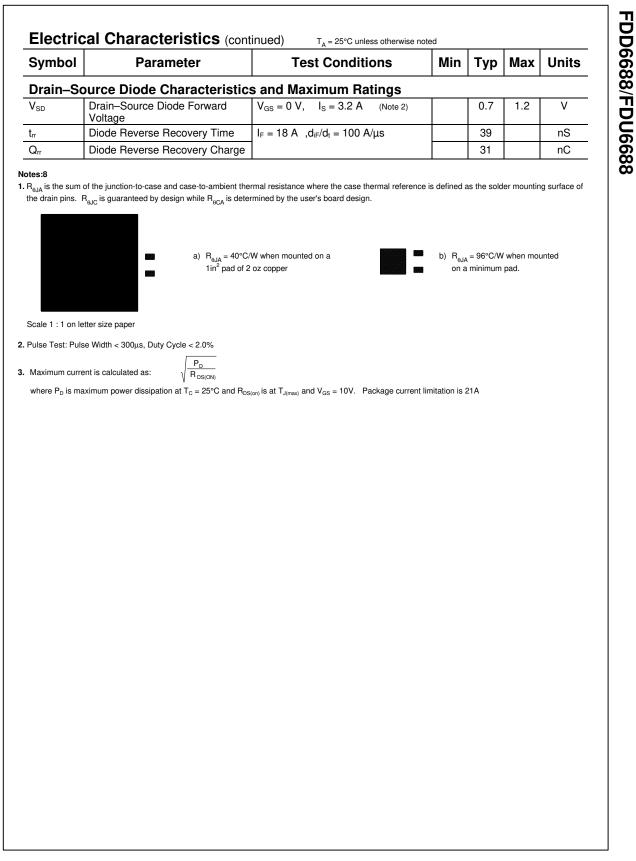
Device Marking	Device	Package	Reel Size	Tape width	Quantity
FDD6688	FDD6688	D-PAK (TO-252)	13"	16mm	2500 units
FDU6688	FDU6688	I-PAK (TO-251)	Tube	N/A	75

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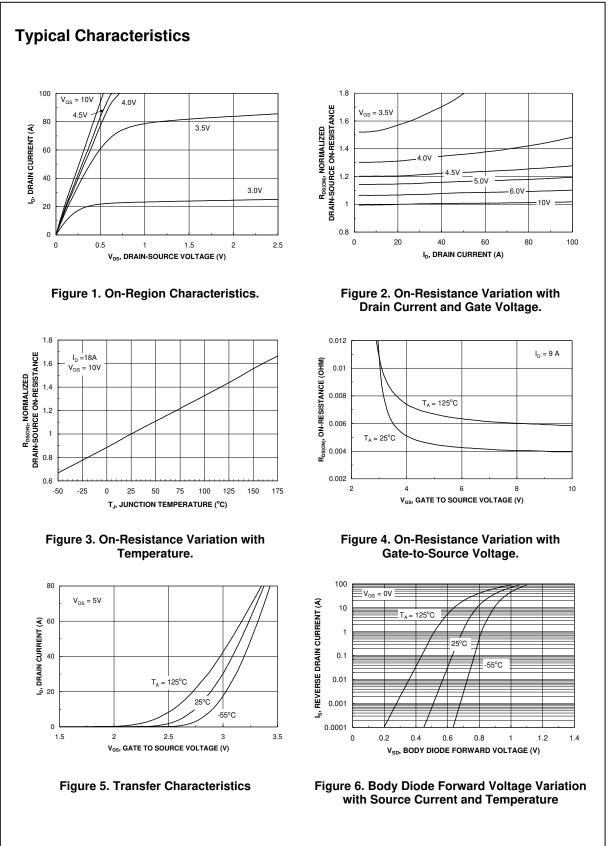
FDD6688/FDU6688

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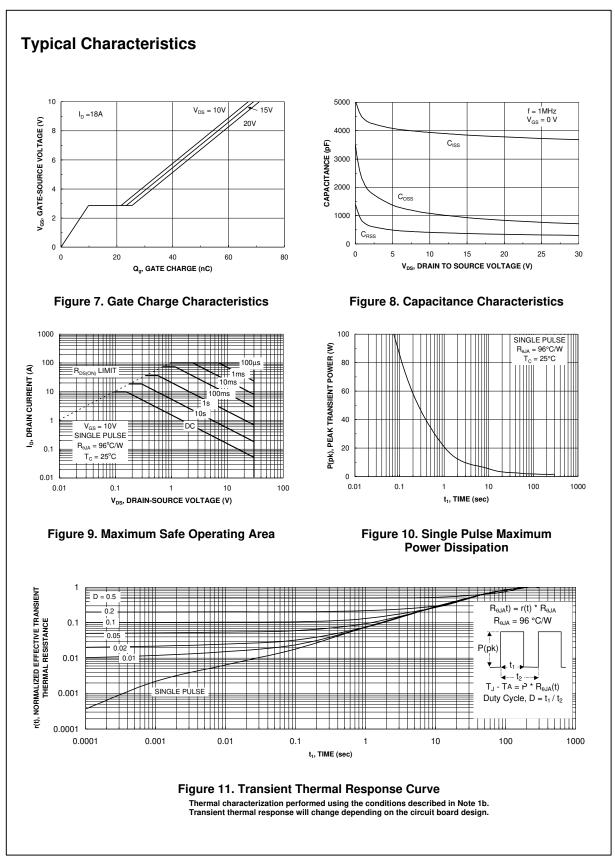
Symbol	Parameter	Test	Conditions	Min	Тур	Max	Units
Drain-So	burce Avalanche Ratings (No	ote 2)					
W _{DSS}	Drain-Source Avalanche Energy	Single Pulse, V	$I_{\rm DD} = 15 \text{ V}, I_{\rm D} = 21 \text{ A}$			370	mJ
I _{AR}	Drain-Source Avalanche Current					21	Α
Off Char	acteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V,$	$I_D = 250 \ \mu A$	30			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_{D} = 250 \ \mu A, R_{0}$	eferenced to 25°C		24		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$,	$V_{GS} = 0 V$			1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 V$,	$V_{DS} = 0 V$			±100	nA
On Char	acteristics (Note 2)						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$,	I _D = 250 μA	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_{D} = 250 \ \mu A, R_{0}$	eferenced to 25°C		-5		mV/°C
$R_{\text{DS(on)}}$	Static Drain-Source On-Resistance	$V_{GS} = 10 V,$ $V_{GS} = 4.5 V,$ $V_{GS} = 10 V.$ In	I _D = 18 A I _D = 16.5 A = 18 A, T _J =125°C		4 5 6	5 6 10	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 V$,	$V_{DS} = 5 V$	50	0	10	А
g _{FS}	Forward Transconductance	$V_{DS} = 5 V$,	I _D = 18 A		88		S
Dvnamio	Characteristics	L					
C _{iss}	Input Capacitance	$V_{DS} = 15 V$,	$V_{GS} = 0 V,$		3845		pF
Coss	Output Capacitance	f = 1.0 MHz			930		pF
C _{rss}	Reverse Transfer Capacitance				368		pF
R _G	Gate Resistance	$V_{GS} = 15 \text{ mV},$	f = 1.0 MHz		1.2		Ω
	g Characteristics (Note 2)				L	I	
t _{d(on)}	Turn-On Delay Time	$V_{DD} = 15 V$,	$I_{\rm D} = 1 {\rm A},$		15	27	ns
t _r	Turn–On Rise Time	V _{GS} = 10 V,	$R_{GEN} = 6 \Omega$		13	23	ns
t _{d(off)}	Turn–Off Delay Time				62	99	ns
t _f	Turn–Off Fall Time				36	58	ns
Q _g	Total Gate Charge	$V_{DS} = 15V,$	I _D = 18 A,		37	56	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = 5 V$			10		nC
Q _{qd}	Gate–Drain Charge	1			14		nC



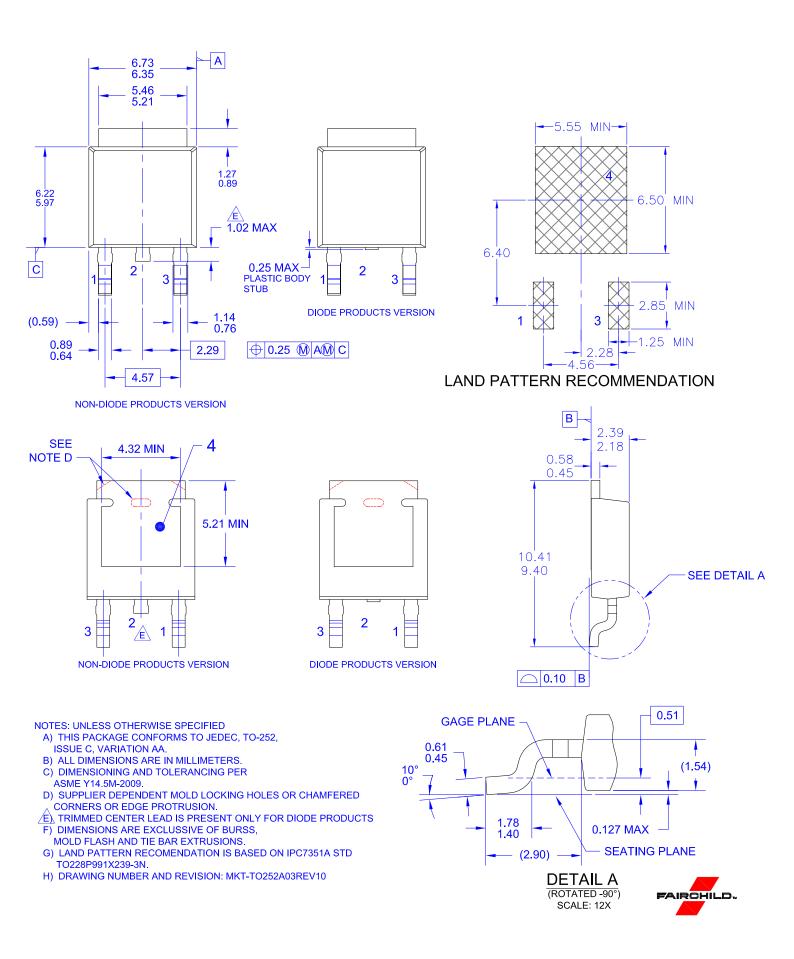
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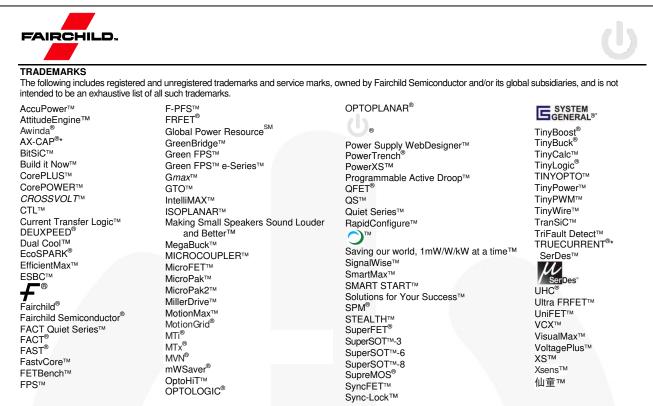


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